

No.911C

LA6458D,6458S

Monolithic Linear IC

High-Performance
Dual Operational Amplifiers

The LA6458 consists of two independent, internally phase compensated operational amplifiers. Application areas include active filters, audio preamplifiers, and various electronic circuits.

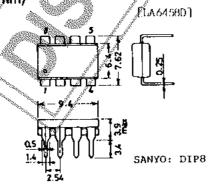
Features

- . LA6458D: 8-pin DIP, LA6458S: 9-pin SEP
- . On-chip phase compensation circuit.
- . High gain, low noise.
- . Slew rate: 1.1V/us typ.

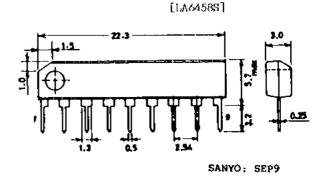
Maximum Ratings at Ta=25°C		unit
Supply Voltage	$V_{\rm CC}/V_{\rm EE}$ /±18	V
Differential Input Voltage	V _{ID} / ±30	v
Common-Mode Input Voltage	V _{IN} // ±15	٧
Allowable Power Dissipation	Pdmax	mW
	// LA6458S // 500	mW
Operating Temperature	Tepr / -20 to +75	°C
Storage Temperature	r _{stq} -40 to +125	°C

Operating Characteristics at Ta=25°C, vec=15v vec=15v	min	typ	max	unit
Input Offset Voltage / VIO RE10kohms/		0.5	G	v_m
Input Offset Current //IIO		5	200	nA
Input Bias Current // In		60	500	nΑ
Common-Mode Input Voltage Vica	±12	±14		V
Common-Mode Rejection Ratio CMR	70	90		dВ
Voltage Gain VGo R _I ≧2kohms,Vo=±10V	86	100		dВ
Maximum Output Voltage Vo Rr≥10kohms	±12	±14		V
Rr ≥2kohms	<u>+</u> 10	± 13		V
Slew Rate SR ØG=0,R _I ≧2kohms		1.1		V/µ8
Equivalent Input Noise VN1 R _s =1kohm, B. P. F=10Hz	to	1.7		μV
Voltage V _{N1} 30kHz				
Current Dissipation I _{Co}		3.5	6	mΑ
Supply Voltage Rejection SVR Rs≦10kohms		30	150	μV/V

Package Dimensions 3001B-D81C (unit mm)

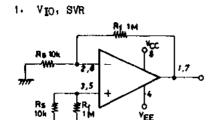


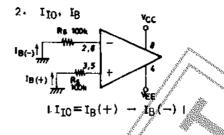
Package Dimensions 3017B-S9IC (unit: mm)

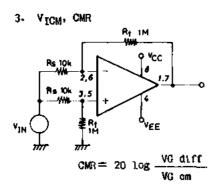


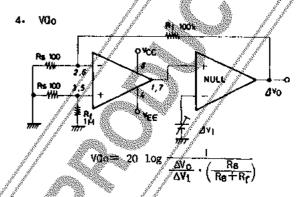
SANYO Electric Co., Ltd. Semiconductor Business Headquarters TOKYO OFFICE Tokyo Bldg., 1-10,1 Chome, Ueno, Taito-ku, TOKYO, 110 JAPAN

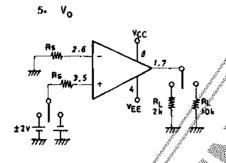
Test Circuits(Pin assignment: DIP)

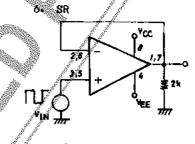


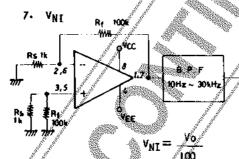


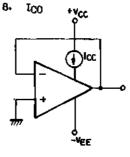


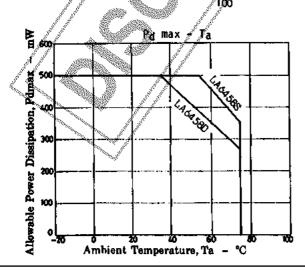




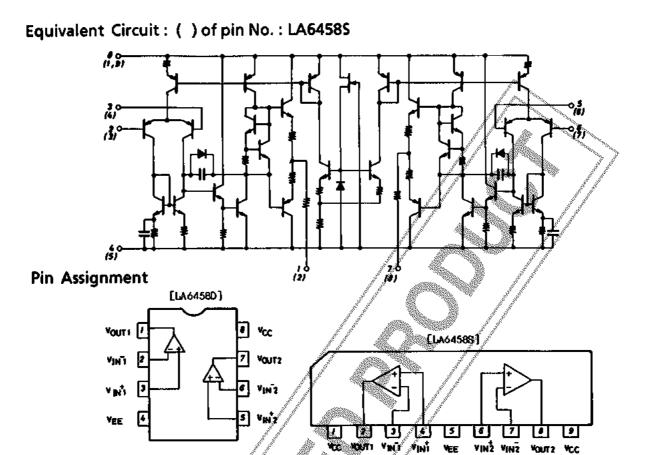








Unit (resistance: Ω)



Sample Application Circuit/RIAA preamplifier (VG=32.5dB)

0.0022u

